

Unidirectional ESD protection diode

Rev. 1 — 11 May 2011

Product data sheet

1. Product profile

1.1 General description

Unidirectional ElectroStatic Discharge (ESD) protection diode designed to protect one signal line from the damage caused by ESD and other transients. The device is housed in a SOD882D leadless ultra small Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

1.2 Features and benefits

- ESD protection of one line
- Ultra small SMD plastic package
- Solderable side pads
- Package height typ. 0.37 mm
- Low clamping voltage: V_{CL} = 19 V
- AEC-Q101 qualified

1.3 Applications

- Computers and peripherals
- Audio and video equipment
- Communication systems
- Portable electronics

1.4 Quick reference data

Table 1. Quick reference data

$T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RWM}	reverse standoff voltage		-	-	12	V
C _d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V}$	-	38	75	pF

- ESD protection up to 30 kV
- IEC 61000-4-2; level 4 (ESD)
- IEC 61000-4-5 (surge); I_{PP} = 5 A
- Max. peak pulse power: P_{PP} = 150 W
- Ultra low leakage current: I_{RM} < 1 nA



Unidirectional ESD protection diode

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	cathode	[1]	
2	anode		1 2 006aaa152
		Transparent top view	

3. Ordering information

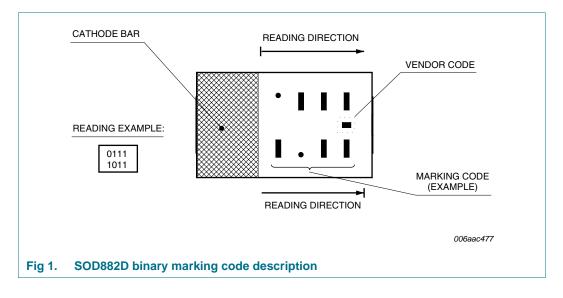
Table 3. Ordering	g information	on	
Type number	Package		
	Name	Description	Version
PESD12VS1ULD	-	leadless ultra small plastic package; 2 terminals; body $1 \times 0.6 \times 0.4$ mm	SOD882D

4. Marking

Table 4. Marking codes	
Type number	Marking code ^[1]
PESD12VS1ULD	1010 0000

[1] For SOD882D binary marking code description, see Figure 1.

4.1 Binary marking code description



PESD12VS1ULD Product data sheet

Unidirectional ESD protection diode

Limiting values 5.

Table 5. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P _{PP}	peak pulse power	$t_p = 8/20 \ \mu s$	<u>[1]</u> _	150	W
I _{PP}	peak pulse current	$t_{p} = 8/20 \ \mu s$	<u>[1]</u> _	5	А
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

Table 6. **ESD** maximum ratings

 $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified.

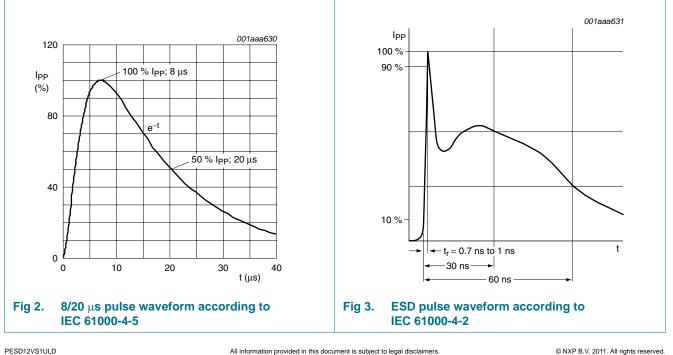
Symbol	Parameter	Conditions	Min	Max	Unit
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	<u>[1][2]</u> _	30	kV
		MIL-STD-883 (human body model)	<u>[2]</u> _	10	kV

[1] Device stressed with ten non-repetitive ESD pulses.

[2] Measured from pin 1 to 2.

Table 7. **ESD** standards compliance

Standard	Conditions
IEC 61000-4-2; level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV



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Unidirectional ESD protection diode

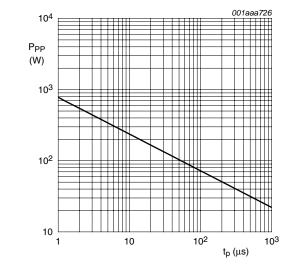
6. Characteristics

Table 8. $T_{amb} = 25$	Characteristics © <i>C</i> unless otherwise spe	cified.					
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{RWM}	reverse standoff voltage			-	-	12	V
I _{RM}	reverse leakage current	V _{RWM} = 12 V		-	< 1	50	nA
V_{BR}	breakdown voltage	I _R = 5 mA		14.7	15	15.3	V
C _d	diode capacitance	$f = 1 MHz; V_R = 0 V$		-	38	75	pF
V _{CL}	clamping voltage		[1][2]				
		I _{PP} = 1 A		-	-	19	V
		I _{PP} = 5 A		-	-	35	V
r _{dyn}	dynamic resistance	I _R = 10 A	[3]	-	0.6	-	Ω

[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

[2] Measured from pin 1 to 2.

[3] Non-repetitive current pulse, Transmission Line Pulse (TLP) t_p = 100 ns; square pulse; ANS/IESD STM5-1-2008.



T_{amb} = 25 °C

Fig 4.Peak pulse power as a function of exponential
pulse duration; typical values

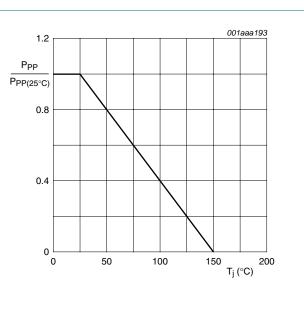
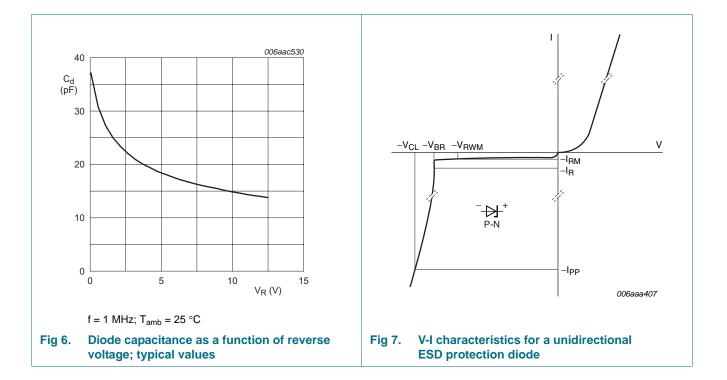


Fig 5. Relative variation of peak pulse power as a function of junction temperature; typical values

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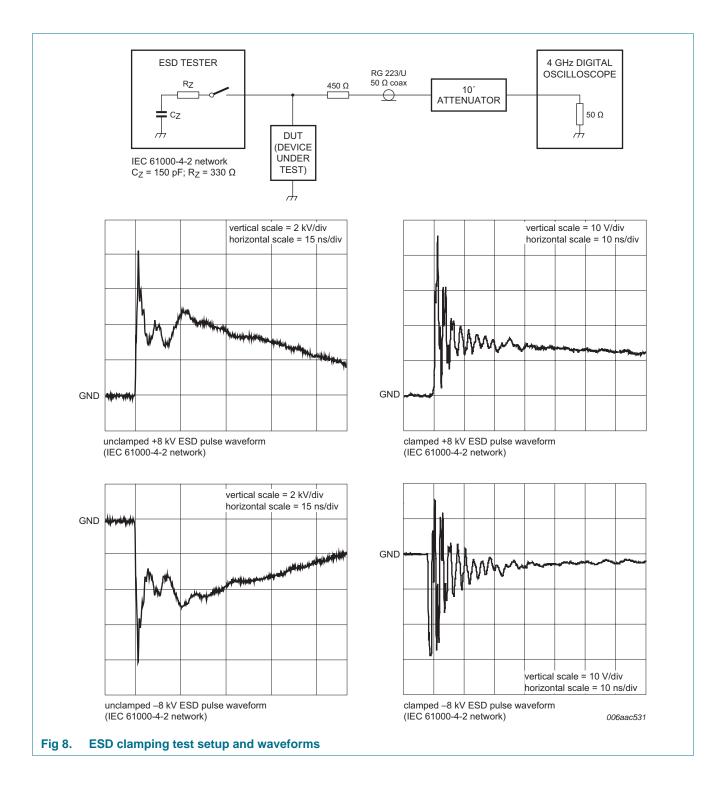
Unidirectional ESD protection diode



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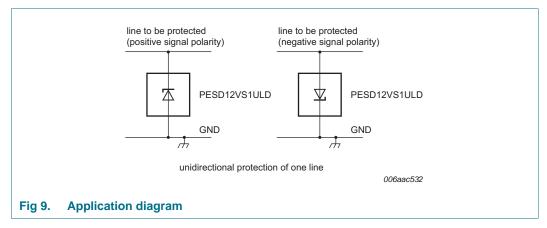


6 of 12

Unidirectional ESD protection diode

7. Application information

The PESD12VS1ULD is designed for the protection of one unidirectional data or signal line from the damage caused by ESD and surge pulses. The device may be used on lines where the signal polarities are either positive or negative with respect to ground. The PESD12VS1ULD provides a surge capability of 150 W per line for an 8/20 μ s waveform.



Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the PESD12VS1ULD as close to the input terminal or connector as possible.
- 2. The path length between the PESD12VS1ULD and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

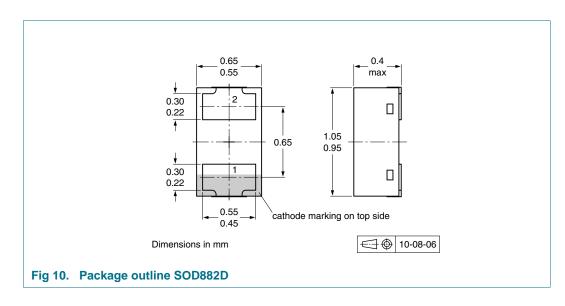
8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

Unidirectional ESD protection diode

9. Package outline



10. Packing information

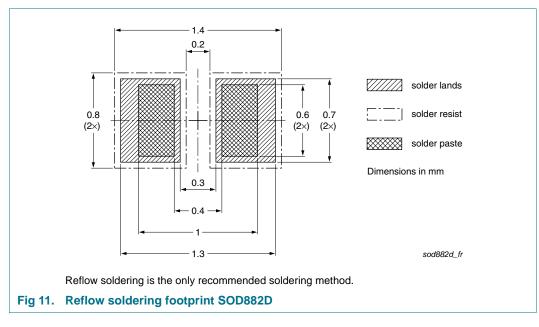
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			10000
PESD12VS1ULD	SOD882D	2 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

11. Soldering



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PESD12VS1ULD

Unidirectional ESD protection diode

12. Revision history

Table 10. Revision history						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
PESD12VS1ULD v.1	20110511	Product data sheet	-	-		

Unidirectional ESD protection diode

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Unidirectional ESD protection diode

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11 of 12

Unidirectional ESD protection diode

15. Contents

1	Product profile 1
1.1	General description 1
1.2	Features and benefits 1
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 2
4.1	Binary marking code description 2
5	Limiting values 3
6	Characteristics 4
7	Application information 7
8	Test information 7
8.1	Quality information 7
9	Package outline 8
10	Packing information 8
11	Soldering 8
12	Revision history
13	Legal information 10
13.1	Data sheet status 10
13.2	Definitions 10
13.3	Disclaimers
13.4	Trademarks 11
14	Contact information 11
15	Contents 12

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